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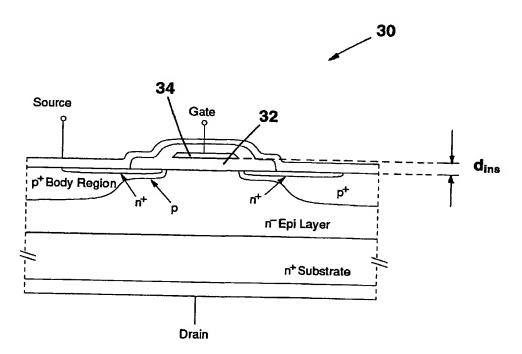
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[Continued on next page]

(54) Title: FAST SWITCHING POWER INSULATED GATE SEMICONDUCTOR DEVICE



(57) Abstract: An insulated gate semiconductor device (30) includes a gate (34), a source terminal, a drain terminal and a variable input capacitance at the gate. A ratio between the input capacitance ( $C_{fiss}$ ) when the device is on and the input capacitance  $C_{iiss}$  when the device is off is less than two and preferably substantially equal to one. This is achieved in one embodiment of the invention by an insulation layer (32) at the gate having an effective thickness  $d_{ins}$  than a minimum thickness.

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A. CLASSIFICATION OF SUBJECT MATTER IPC 7 H01L29/78 H01L29/423

H03K17/04

According to International Patent Classification (IPC) or to both national classification and IPC

#### B. FIELDS SEARCHED

 $\begin{array}{ll} \mbox{Minimum documentation searched (classification system followed by classification symbols)} \\ \mbox{IPC 7} & \mbox{H01L} & \mbox{H03K} \end{array}$ 

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Electronic data base consulted during the international search (name of data base and, where practical, search terms used)

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<b>X</b>	WO 02/13257 A (TIHANYL JENOE; HIRLER FRANZ (DE); WERNER WOLFGANG (DE); INFINEON TECH) 14 February 2002 (2002-02-14) page 4, line 5 - line 12 page 15, line 1 - line 28; figure 5	1-8,10	
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	<b>-/-</b> -		
X Furth	er documents are listed in the continuation of box C.  X Patent family members are listed in	n annex.	

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Date of the actual completion of the international search  8 July 2004	Date of mailing of the international search report  22/07/2004
Name and mailing address of the ISA  European Patent Office, P.B. 5818 Patentlaan 2  NL – 2280 HV Rijswijk  Tel. (+31–70) 340–2040, Tx. 31 651 epo nl,  Fax: (+31–70) 340–3016	Authorized officer Lantier, R

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J.,	addition, more appropriate, or the relevant passages	Relevant to claim No.
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